

UNR412X, UNR412Y (UN412X, UN412Y)

Silicon PNP epitaxial planar type

For digital circuits

■ Features

- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- Allowing supply with the radial taping

■ Resistance by Part Number

	(R ₁)	(R ₂)
• UNR412X (UN412X)	0.27 kΩ	5 kΩ
• UNR412Y (UN412Y)	3.1 kΩ	4.6 kΩ

■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-50	V
Collector-emitter voltage (Base open)	V _{CEO}	-50	V
Collector current	I _C	-500	mA
Total power dissipation	P _T	300	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

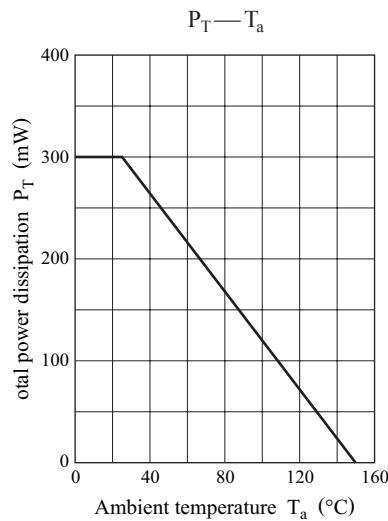
■ Electrical Characteristics T_a = 25°C ± 3°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	I _C = -10 μA, I _E = 0	-50			V
Collector-emitter voltage (Base open)	V _{CEO}	I _C = -2 mA, I _B = 0	-50			V
Collector-base cutoff current (Emitter open)	UNR412X UNR412Y	I _{CBO} V _{CB} = -50 V, I _E = 0			-0.1	μA
Collector-emitter cutoff current (Base open)					-1	
Emitter-base cutoff current (Collector open)	I _{EBO}	V _{EB} = -6 V, I _C = 0			-2	mA
Forward current transfer ratio	UNR412X UNR412Y	h _{FE} V _{CE} = -10 V, I _C = -100 mA	20			—
Collector-emitter saturation voltage			50			
Output voltage high-level	V _{OH}	V _{CC} = -5 V, V _B = -0.5 V, R _L = 500 Ω	-4.9			V
Output voltage low-level	V _{OL}	V _{CC} = -5 V, V _B = -3.5 V, R _L = 500 Ω			-0.2	V
Input resistance	UNR412X UNR412Y	R ₁		-30%	0.27	+30%
Resistance ratio				-30%	3.1	+30%
Transition frequency	f _T	V _{CB} = -10 V, I _E = 1 mA, f = 200 MHz		0.043	0.054	0.065
					0.67	—
					200	MHz

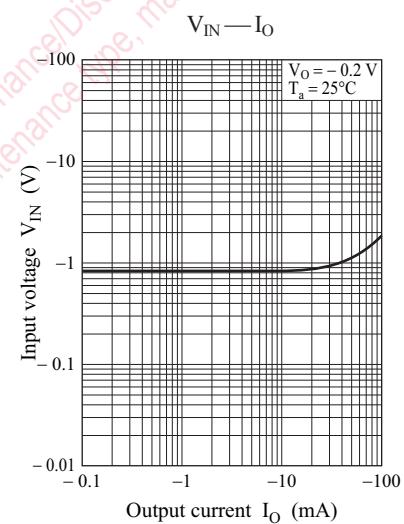
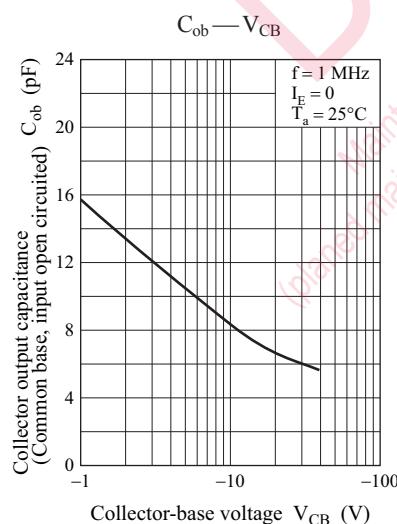
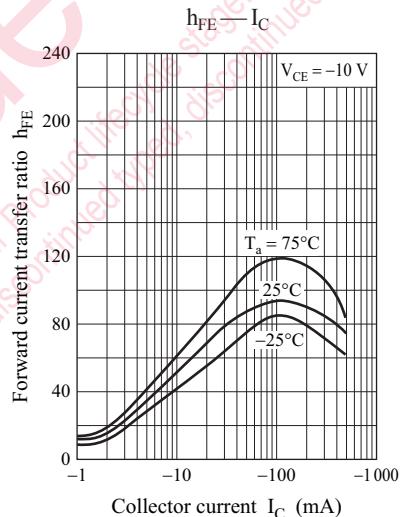
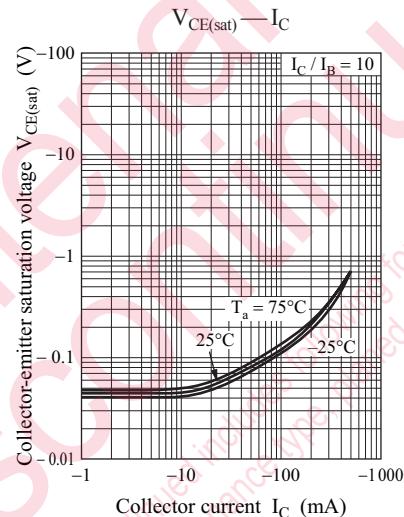
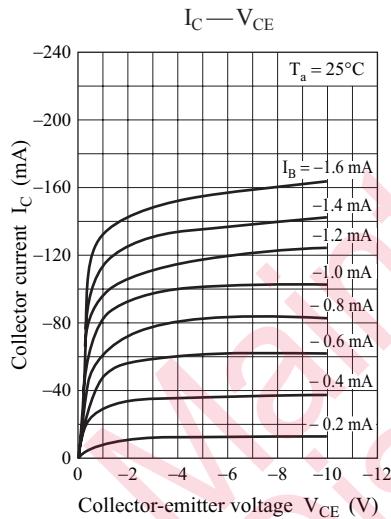
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Note) The part numbers in the parenthesis show conventional part number.

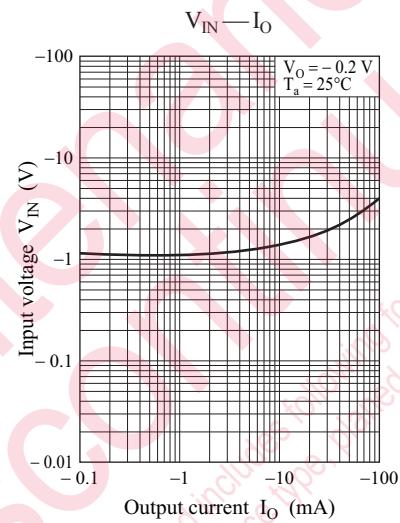
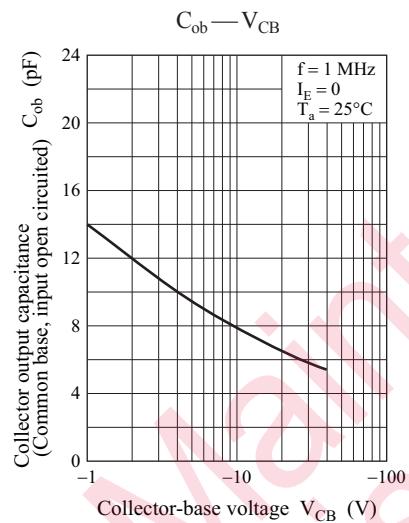
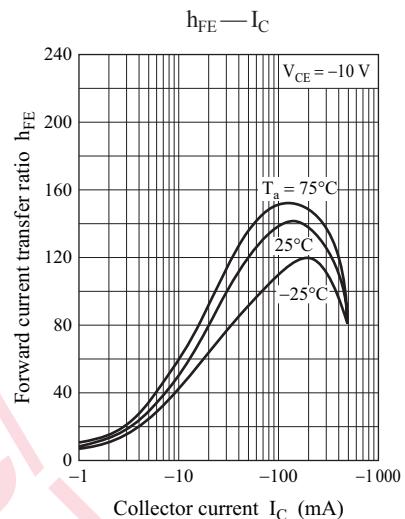
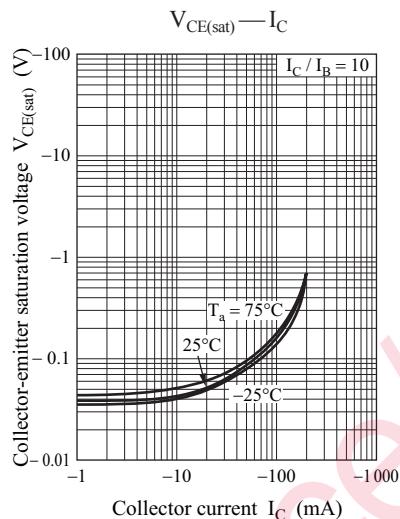
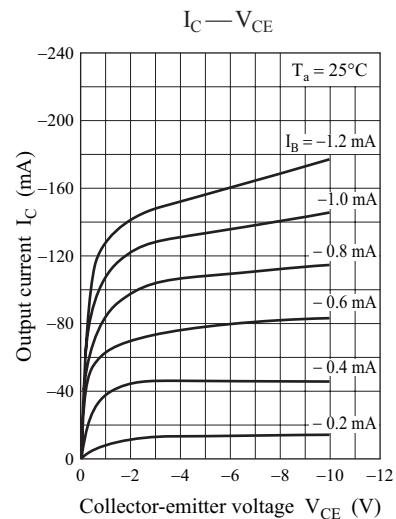
Common characteristics chart



Characteristics charts of UNR412X



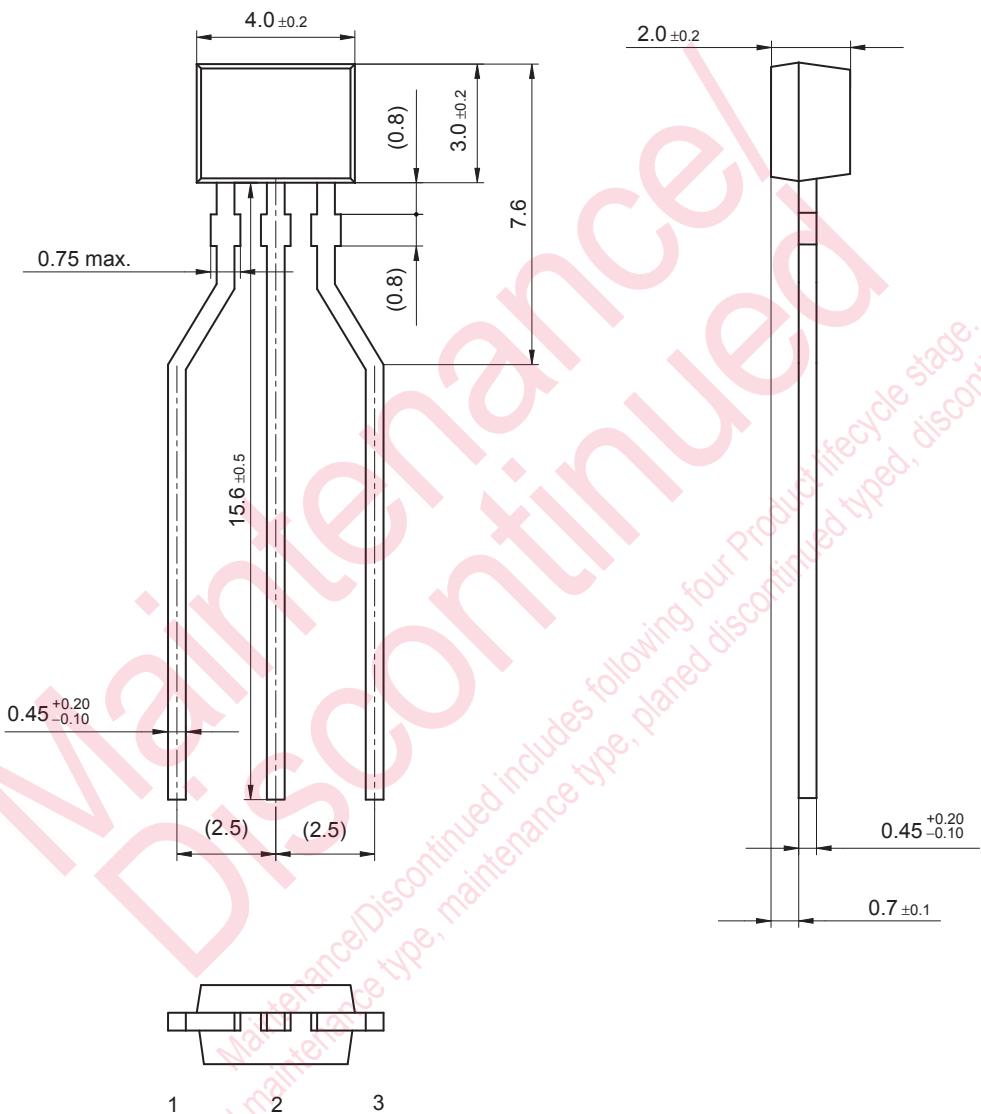
Characteristics charts of UNR412Y



Maintenance/Discontinued products
(planned maintenance type, maintenance period, discontinued type)

NS-B1

Unit: mm



Maintenance Discontinued
(planned maintenance type, maintenance type, discontinued includes following four Product lifecycle stage:
discontinued type, planned discontinued type, discontinued type, discontinued type)

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